

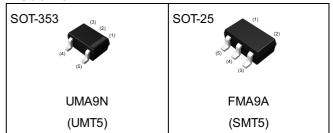
Emitter common(dual digital transistors)

Parameter	DTr1 and DTr2
V _{CC}	-50V
I _{C(MAX.)}	-100mA
R ₁	10kΩ
R_2	10kΩ

Features

- 1)Two DTA114E chips in UMT and SMT packages.
- 2) Mounting cost and area can be cut in half.

Outline



•Inner circuit

UMA9N

- (1) DTr1 IN(Base)
- (2) DTr1 / DTr2 GND(Emitter)
- (3) DTr2 IN(Base)
- (4) DTr2 OUT(Collector)
- (5) DTr1 OUT(Collector)
- DTr1 DTr2

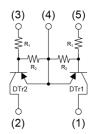
 R₂ R₃

 R₄

 (1) (2) (3)

FMA9A

- (1) DTr1 OUT(Collector)
- (2) DTr2 OUT(Collector)
- (3) DTr2 IN(Base)
- (4) DTr1 / DTr2 GND(Emitter)
- (5) DTr1 IN(Base)



Application

INVERTER, INTERFACE, DRIVER

Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
UMA9N	SOT-353 (UMT5)	2021	TR	180	8	3000	A9
FMA9A	SOT-25 (SMT5)	2928	T148	180	8	3000	A9

● Absolute maximum ratings (T_a = 25°C)

<For DTr1 and DTr2 in common>

Parameter			Values	Unit
Supply voltage			-50	V
Input voltage			-40 to 10	V
Output current			-50	mA
Collector current			-100	mA
Power dissipation	UMA9N	P _D *2*3	150	::::\\//T- t-:
	FMA9A	P _D *2*4	300	mW/Total
Junction temperature		Tj	150	°C
Range of storage temperature		T _{stg}	-55 to +150	°C

● Electrical characteristics (T_a = 25°C)

<For DTr1 and DTr2 in common>

Daramatar	Cymph al	Conditions	Values			11.26	
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
long it valtage	$V_{I(off)}$	$V_{CC} = -5V, I_{O} = -100\mu A$	-	-	-0.5	V	
Input voltage	V _{I(on)}	$V_O = -0.3V$, $I_O = -10$ mA	-3	-	-		
Output voltage	V _{O(on)}	I _O = -10mA, I _I = -0.5mA	-	-100	-300	mV	
Input current	I _I	V _I = -5V	-	-	-880	μA	
Output current	I _{O(off)}	V _{CC} = -50V, V _I = 0V	-	-	-500	nA	
DC current gain	G _l	$V_O = -5V, I_O = -5mA$	30	-	-	-	
Input resistance	R ₁	-	7	10	13	kΩ	
Resistance ratio	R ₂ /R ₁	-	8.0	1.0	1.2	-	
Transition frequency	f _T *1	V _{CE} = -10V, I _E = 5mA, f = 100MHz	-	250	-	MHz	

^{*1} Characteristics of built-in transistor.

^{*2} Each terminal mounted on a reference land.

^{*3 120}mW per element must not be exceeded.

^{*4 200}mW per element must not be exceeded.

● Electrical characteristic curves (T_a = 25°C)

<For DTr1 and DTr2 in common>

Fig.1 Input Voltage vs. Output Current (ON Characteristics)

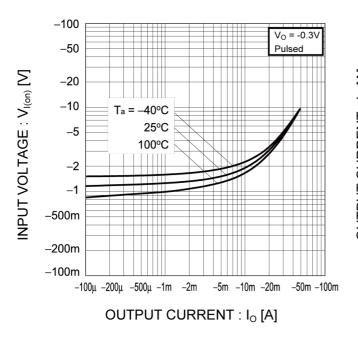


Fig.2 Output Current vs. Input Voltage (OFF Characteristics)

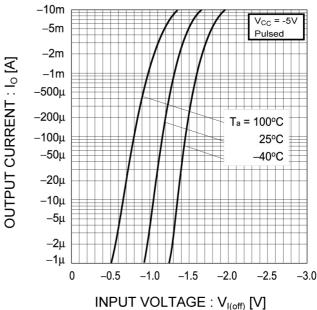


Fig.3 Output Current vs. Output Voltage

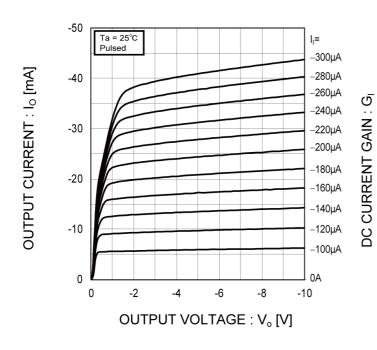
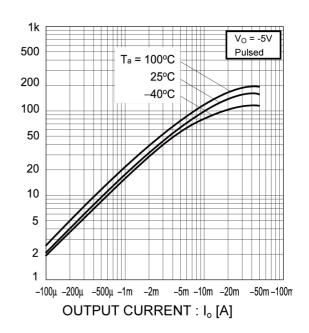


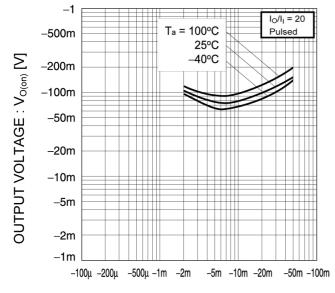
Fig.4 DC Current Gain vs. Output Current



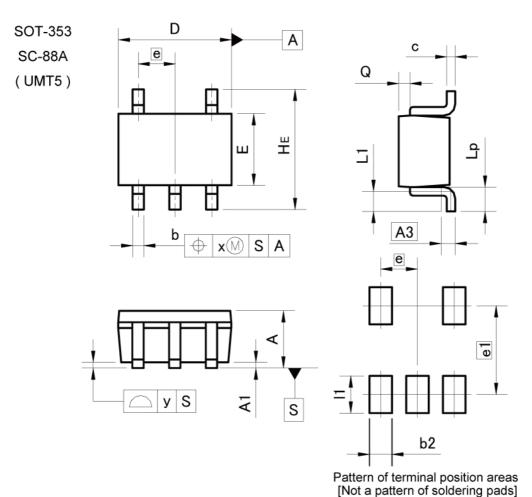
● Electrical characteristic curves (T_a = 25°C)

<For DTr1 and DTr2 in common>

Fig.5 Output Voltage vs. Output Current



Dimensions



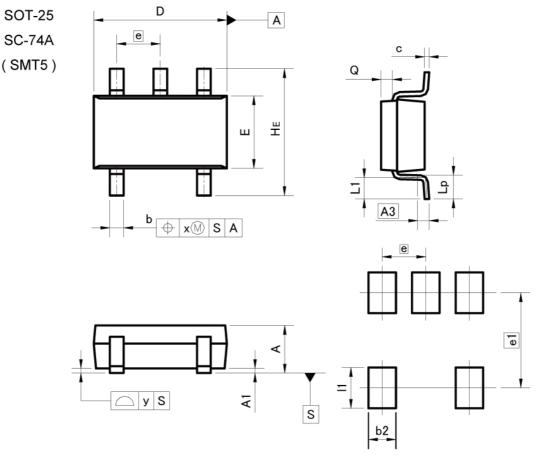
MILIMETERS INCHES DIM MIN MIN MAX Α 0.039 0.80 1.00 0.031 Α1 0.00 0.10 0.000 0.004 0.25 0.010 A3 0.15 0.30 0.006 0.012 b С 0.10 0.20 0.004 0.008 D 1.90 2.10 0.075 0.083 Ε 1.15 1.35 0.045 0.053 е 0.65 0.026 HΕ 2.00 2.20 0.079 0.087 L1 0.20 0.50 0.008 0.020 0.010 0.022 Lp 0.25 0.55 Q 0.004 0.012 0.10 0.30 0.004 0.10 Х 0.10 0.004

DIM	MILIM	ETERS	INCHES		
	MIN	MAX	MIN	MAX	
b2	- 1	0.40	-	0.016	
e1	1.5	55	0.0	61	
11	-	0.65	-	0.026	

Dimension in mm/inches



Dimensions



Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIM	ETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	1.00	1.30	0.039	0.051
A1	0.00	0.10	0.000	0.004
A3	0.3	25	0.010	
b	0.25	0.40	0.010	0.016
С	0.09	0.25	0.004	0.010
D	2.80	3.00	0.110	0.118
Е	1.50	1.80	0.059	0.071
е	0.9	0.95		37
HE	2.60	3.00	0.102	0.118
L1	0.30	0.60	0.012	0.024
Lp	0.40	0.70	0.016	0.028
Q	0.20	0.30	0.008	0.012
x		0.20	-	0.008
У	-0.	0.10	-//	0.004

-	DIM	MILIM	MILIMETERS		INCHES		
		MIN	MAX	MIN	MAX		
	b2	-	0.60	=:	0.024		
	e1	2.	10	0.0	83		
	11	-	0.90	=	0.035		

Dimension in mm/inches



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